Revealing charge-tunneling processes between a quantum dot and a superconducting island through gate sensing

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We report direct detection of charge-tunneling between a quantum dot and a superconducting island through radio-frequency gate sensing. We are able to resolve spin-dependent quasiparticle tunneling as well as two-particle tunneling involving Cooper pairs. The quantum dot can act as an RF-only sensor to characterize the superconductor addition spectrum, enabling us to access subgap states without transport. Our results provide guidance for future dispersive parity measurements of Majorana modes, which can be realized by detecting the parity-dependent tunneling between dots and islands.

Quantum dots coupled to superconductors can give rise to novel physical phenomena such as π and φ0-junctions [1,2]. Cooper pair splitting [3,4], and Yu-Shiba-Rusinov (YSR) states [5,6]. These phenomena arise because the single-electron states of the dot hybridize with the more complicated many-particle states of the superconductor. Recently, such hybrid systems have gained interest in the context of Majorana zero modes (MZMs) where the quantum dot (QD) can, for example, be used as a spectrometer [8]. Moreover, projective parity measurements can be achieved by coupling a QD to a pair of MZMs, which are located on a superconducting island (SC) [9,10], enabling topologically protected quantum computation. These projective measurements rely on the parity-dependent hybridization between a single dot level and the MZMs [11,12]. Therefore, unambiguous detection of coherent tunneling between a QD and a superconducting island is needed to implement this read-out.

Dispersive gate sensing (DGS) provides direct access to charge hybridization between weakly coupled dots or islands. More precisely, tunneling within these structures can impart a frequency shift on a resonant circuit that can be observed on short time scales with high accuracy. In this way, experiments have revealed coherent charge hybridization between superconductors [13,14] and in semiconductor double quantum dots [15,16]. Moreover, capacitive RF sensing has been used to study charging of QDs connected to normal and superconducting reservoirs [17,18]. As such, DGS presents an excellent opportunity for studying charge-tunneling in hybrid structures containing QDs.

In this paper, we report direct detection of different types of charge-tunneling processes between a QD and a SC through DGS on the QD. From observations of the resonator response, supported by numerical simulations, we find that the nature of the tunneling depends crucially on the ordering of the relevant energy scales of the SC. When the smallest scale is the energy of the lowest single-particle state, the QD and SC can exchange quasiparticles, giving rise to the characteristic ‘even-odd’ effect. Conversely, when the charging energy of the SC is lowest, we detect signatures of Cooper pairs tunneling out of the SC. Depending on the tunneling amplitude, this results in either 1e-charging of the QD, with the other electron leaving into a reservoir, or 2e-charging of the QD. Tunneling to the single-particle states can, however, be re-enabled by operating the device in a floating regime where the total number of charges in the two systems is conserved. These results show that DGS allows us to effectively perform RF-only tunneling spectroscopy on the SC. To this end, we use the QD and resonator as a probe to characterize a subgap state in the SC without need for transport via leads.

A schematic of our experiment is shown in Fig. 1a,b. Two charge islands are formed in an InAs nanowire with an epitaxially grown Al-shell. A superconducting island is defined by removing the Al outside a 1.2µm segment with wet-etching. Tunneling barriers are implemented with gates, insulated from the wire by 10nm AlOx. They are used to define the QD and SC; and to control the various tunneling rates. Large-lever arm top gates (‘plungers’) on both QD and SC can be used to tune the chemical potentials. The dot plunger is connected to an off-chip, superconducting resonator with a resonance frequency of 449.5 (443.2) MHz for device A (B) (Supplemental Material) [22]. We use its response near the resonance frequency to probe charge tunneling on and off the dot. All measurements are done at temperatures of T ≈ 20 mK and at zero magnetic field unless otherwise indicated.

The relevant energy scales in our devices can be obtained from Coulomb blockade measurements: Figure 1c shows Coulomb diamonds of the superconducting island alone, measured through conductance. The diamonds of device A display a clear even-odd pattern, indicating...
that the energy of the lowest odd-parity state, $E_0$, is smaller than the charging energy of the superconducting island, $E_C = \frac{e^2}{2C_S}$, where $C_S$ is the total capacitance of the SC (Fig. 1d) \cite{23, 24}. For this device, we estimate $E_0 = 72\, \mu eV$ and $E_C = 112\, \mu eV$ from the extent of the diamonds. Conversely, the charging of the superconducting island of device B is 2$e$-periodic, indicating that $E_0 > E_C$ \cite{23, 24}; here, we estimate $E_0 \approx 90\, \mu eV$ and $E_C \approx 70\, \mu eV$. While in an ideal BCS superconductor $E_0$ is equal to the superconducting gap $\Delta$, current measurements on device A (Supplemental Material) and the negative differential conductance observed in device B indicate the presence of subgap states \cite{9}. In both devices, the charging energy of the dot, $E_{\text{CQD}} \approx 200 – 300\, \mu eV$, is the largest energy scale in the system, and the typical QD level spacing exceeds the thermal energy (Supplemental Material).

In the following, we investigate the change in resonator...
response when charges are able to tunnel between the QD and SC at zero bias, beginning with device A. To this end, we form a hybrid double dot by tuning the gates T1 and T2 close to pinch-off, and T3 into pinch-off. Figures 2a,b show the resonator response as a function of gates T1 and T2 close to pinch-off, and T3 into pinch-off. This transition involves a reservoir with a continuous spectrum, indicated by the shaded region above the lowest available energy state. The schematic shows how these states couple via crossed Andreev reflection. c) Same as in a) for the strongly coupled regime. Dashed pink lines: locations of the lead transitions from the (-2,-1) and (0,-1) states as a guide to the eye. d) Linecuts of the phase (green) and amplitude (blue) along the (2,-2) to (0,0) interdot transition, with a fit to a quantum capacitance model in black [26]. These states couple via Cooper pair tunneling.

We focus on the interdot transitions, highlighted in Figs. 2a-c, where we observe a strong amplitude and phase response on all charge degeneracy points. Interestingly, we see a strong difference in the resonator response across interdot transitions with a different parity of the total particle number, indicating a difference between the coupling between the involved states [26].

This dependence on total parity can be understood as a spin-dependent tunnel coupling [26]. To see this, we label the states according to their pairing; for the SC states as even/odd, and for the QD states as singlet/doublet: |e,o,S/D⟩, |o,e,S/D⟩. We can differentiate couplings between two sets of states: |e,D⟩ to |o,S⟩ and |e,S⟩ to |o,D⟩. The coupling is different for these two sets because of spin degeneracy: From |e,S⟩ either of the two electrons forming the singlet can tunnel with equal probability, giving rise to a two-fold degeneracy in the coupling between |e,S⟩ and |o,D⟩, i.e., between the states with total even parity. On the other hand, from |e,D⟩ only one of the two electrons can tunnel from QD to SC due to Pauli exclusion; in this case no degeneracy is present. As a result, the transition rate between states of total even parity is expected to be $\sqrt{2}$ times stronger than between states of total odd parity, corresponding to a $\sqrt{2}$ times smaller frequency shift.

We can model the phase response across the interdot transition by considering the quantum capacitance arising from the hybridization of the associated charge states [26]. However, by just using the phase data we are not able to confirm the expected tunnel coupling difference between the two cases (Fig. 2c). We attribute this mismatch to the asymmetric frequency response of the resonator, arising from imperfect impedance matching [27]. To obtain quantitative agreement, we measure the frequency-dependent resonator response at a pair of interdot transitions that show this parity effect (Fig. 2d). From fits to the resonator responses we extract frequency shifts with a ratio of $(f_0 - f_{\text{odd}})/(f_0 - f_{\text{even}}) = 1.46 \approx \sqrt{2}$, consistent with the expected spin-dependent tunneling amplitude.

For device B, the situation changes significantly. The
energy ordering $E_0 > E_{SC}^S$ implies that quasiparticle 
states are not accessible (Fig. 1d). We form a hybrid
double dot by tuning T1, T2, and T3 close to pinchoff.
The CSD for a weak QD-SC coupling is shown in Fig. 3a.
The diagram is 2e-periodic in the SC gate, indicating 
that the island is charged via Andreev reflections from 
the lead. The QD is again 1e-periodic. To model the 
measured CSDs, we compute the charge ground state 
by diagonalizing an effective Hamiltonian of the system 
that includes charging effects, the superconducting gap 
in the island, and coupling terms (Supplemental Material).
This model, with the energy scales extracted from the 
Coulomb blockade measurements and an adjustable tun-
neling amplitude (rightmost panel in Fig. 3a), describes 
the observed CSD well.

The different gate charge periodicity for the QD and 
SC leads to interdot transitions that change the total 
charge of the dot-island system. This implies that a 
reservoir must be involved in the corresponding charge-
transfer process. The observed resonator signal, with a 
linecut shown in Fig. 3b, results from tunneling on and off 
the QD, and thus should not contain information of SC-
lead coupling [26]. A possible candidate for the precise 
underlying process that gives rise to our data is crossed 
Andreev reflection (CAR) [4, 5]. There, a hole from the 
QD is converted to an electron in the lead, consistent 
with the charge states involved in the experiment. This 
process is exponentially suppressed in the length of the 
island $\exp(-L/\xi)$, where $\xi$ is the superconducting co-
herence length [29]. Still, with $L = 1.2 \mu$m and assuming 
a coherence length of $\xi \sim 260 \text{ nm}$ [10] this remains a 
plausible scenario.

Interestingly, increasing the tunnel coupling allows for 
bringing the system into a regime where a particle-
conserving interdot transition emerges. The CSD in a 
more strongly coupled regime, together with a simula-
tion of the charge ground states is shown in Fig. 3c. In 
this regime, we assume an induced gap in the quantum 
dot, consistent with earlier studies in the context of YSR 
states [2]. Here, we observe that the regions with odd 
charge number in the QD shrink, while the regions with 
an even number of QD charges connect, resulting in an 
even-odd pattern in both gates. Now, the interdot transi-
tion appears purely dispersive (Fig. 3d): we observe only 
a small phase shift, without any amplitude response. By 
fitting the quantum capacitance model to this phase shift, 
we find $t_{CP} = 260 \text{ µeV}$. Overall, our data is consistent 
with coherent Cooper pair transfer between the dot and 
the island.

As we have seen, the main difference between the two 
deVICES is that the odd states of the SC can not be di-
rectly accessed in the regime $E_0 > E_{SC}^S$. This changes in 
absence of lead reservoirs because quasiparticles that tun-
nel from the QD onto the SC are confined to the system 
[15]. The additional energy associated with decharging 
the QD makes Cooper pair tunneling energetically unfa-
vorable when $E_0 < E_{SC}^S + E_{CQD}^S$. We realize this situation 
experimentally in device B by closing the outer tunnel 
barriers, through gates T1 and T3. The resulting CSD 
and corresponding calculation of the ground state transi-
tions are shown in Figs. 4a,b. It can readily be seen that 
no transitions to a reservoir take place, and the even-odd 
pattern is indicative of the alternating occupation of even 
and odd states of the SC.

Importantly, even though SC and QD are now gal-
vanically isolated from the environment, the gate sensor 
still allows us to study the quasiparticle states in the SC. 
To show this, we measure the evolution of the even-odd 
spacing as a function of temperature (Fig. 4c). This spac-
ing is a measure for the free energy difference of the SC. 
In particular, the temperature evolution of the free en-
ergy difference can be used to identify and characterize 
subgap states [30]; for proximitized nanowires, this has 
earlier been studied in transport [9]. The extracted free 
energy difference $F_0 - F_a$ as a function of temperature 
is shown in Fig. 4d. A fit to the model from Ref. [9] 
yields a gap of $\Delta = 220 \text{ µeV}$, a supgap state energy of 
$E_0 = 106 \text{ µeV}$, and an Al volume of $V = 2.9 \times 10^3 \text{ nm}^3$, 
consistent with the dimensions of the island. We note

\begin{figure}[h]
\centering
\includegraphics[width=\textwidth]{figure4.png}
\caption{\textbf{Spectroscopy of a subgap state in the floating regime} \textbf{a) Charge stability diagram measured in phase in device B. The diagonal lines indicate that the total charge in the system is conserved. \textbf{b) Calculated positions of the transitions in good agreement with the measured stability diagram. Inset: energy spectrum with even states in black and odd states in green, showing that the even-odd pattern is caused by the parity effect even though $E_0 > E_{SC}^S$. \textbf{c) Temperature dependence of the even-odd pattern. \textbf{d) Evolution of the free energy difference with temperature (black dots), with a fit to the model described in Ref. [9] (green line). The free energy difference is extracted from the even-odd pattern via $F_0 - F_a = (S_e - S_o) e \alpha_{sc}/4$ with $\alpha_{sc} = 0.9$ the lever arm of the SC gate.}}}
\end{figure}
that the slightly larger energy of the subgap state is consistent with the more negative plunger gate voltage for this measurement \cite{31}. The excellent quality of the fit corroborates our initial assessment of the presence of a supgap state (Fig. 1b). This result shows clearly that the resonator response of the QD gate sensor can be used to characterize states of the SC, even when leads for transport experiments are not available.

In summary, we have performed dispersive gate sensing on a quantum dot that can exchange particles with a superconducting island. Analysis of the resonator response has allowed us to directly detect the charge-tunneling processes that take place between the dot and the superconductor. We have directly observed single or multi-particle tunneling processes, depending on the dominating energy scales of the hybrid double dot. Our results show that DGS provides an excellent tool for studying subgap excitations. In particular, using a QD and gate sensor allows performing spectroscopy without transport, which is relevant in cases where particle number should be conserved, such as likely required for qubit devices that operate based on parity. The ability of DGS to resolve differences in tunnel couplings — as seen for the case of spin-dependent tunneling — provides a very simple means for precisely characterizing hybridization while leaving the system in the ground state. Going forward, these demonstrated abilities will be crucial for the realization and operation of Majorana qubits based on proximitized nanowires \cite{11} \cite{12}. Our results thus set the stage for the implementation of quantum measurements of topological qubits.

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